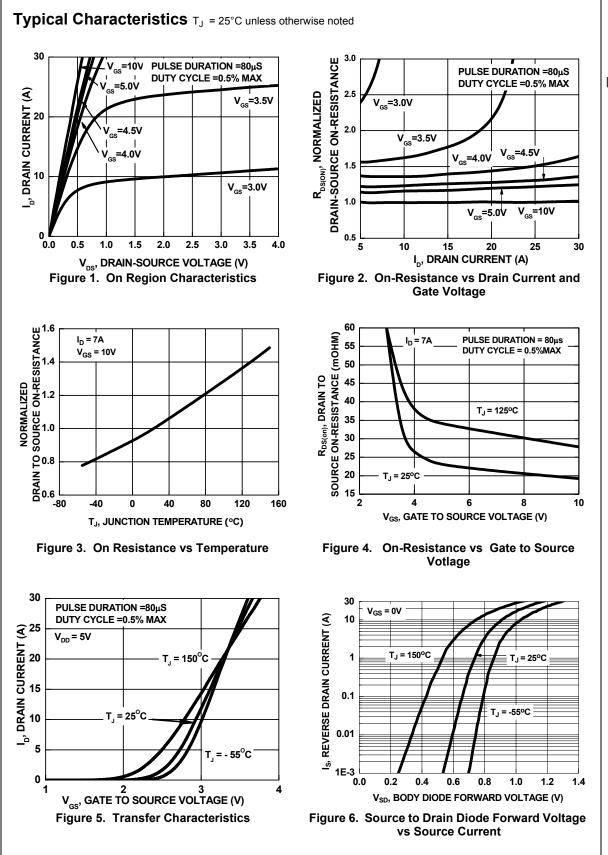


Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	acteristics						
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V	30			V	
∆BV <sub>DSS</sub>	Breakdown Voltage Temperature	$I_{\rm D}$ = 250µA, referenced to					
$\Delta T_J$	Coefficient	25°C		23		mV/°C	
I	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 24V			1		
IDSS	Zero Gate Voltage Drain Current	$V_{GS} = 0V$ $T_J = 125^{\circ}C$			250	μA	
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS}$ = ±20V, $V_{DS}$ = 0V			±100	nA	
On Chara	acteristics (Note 3)						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA	1.2	1.7	2.5	V	
$\Delta V_{GS(th)}$	Gate to Source Threshold Voltage	$I_D = 250 \mu A$ , referenced to			2.0		
$\Delta T_J$	Temperature Coefficient	25°C		- 4.3		mV/°C	
r <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 10V, I <sub>D</sub> = 7A		19	23	mΩ	
		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 6A		24	30		
		V <sub>GS</sub> = 10V, I <sub>D</sub> = 7A,		26	32		
		T <sub>J</sub> = 125°C					
Dynamic	Characteristics						
C <sub>iss</sub>	Input Capacitance			475	635	pF	
C <sub>oss</sub>	Output Capacitance	$V_{DS} = 15V, V_{GS} = 0V,$		100	135	pF	
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1.0MHz		65	100	pF	
R <sub>G</sub>	Gate Resistance	f = 1MHz		0.9	1.6	Ω	
	g Characteristics (Note 3)				10		
t <sub>d(on)</sub>	Turn-On Delay Time Rise Time			5 9	10 18	ns	
t <sub>r</sub>	Turn-Off Delay Time	V <sub>DD</sub> = 15V, I <sub>D</sub> = 7A V <sub>GS</sub> = 10V, R <sub>GS</sub> = 33Ω		9 42	68	ns ns	
t <sub>d(off)</sub> t <sub>f</sub>	Fall Time			21	34	ns	
		V <sub>DS</sub> = 15V, V <sub>GS</sub> = 10V,					
Qg	Total Gate Charge	$I_D = 7A$		9.2	13	nC	
Qq	Total Gate Charge	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 5V,		5.0	7	nC	
Q <sub>gs</sub>	Gate to Source Gate Charge	$I_D = 7A$		1.5		nC	
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			2.0		nC	
Drain-So	urce Diode Characteristics						
		I <sub>SD</sub> = 7A		0.9	1.25	V	
V <sub>SD</sub>	Source to Drain Diode Voltage	$I_{SD} = 2.1A$		0.8	1.0	V	
t <sub>rr</sub>	Diode Reverse Recovery Time	$I_{\rm F} = 7$ A, di/dt = 100A/µs		0.0	33	ns	
Q <sub>rr</sub>	Diode Reverse Recovery Charge				20	nC	
	sum of the junction-to-case and case-to-ambient therma s. $R_{\theta JC}$ is guaranteed by design while $~R_{\theta CA}$ is determine		nce is define	ed as the so	older mounti	ng surface	
Q Q Q	ာ a) 78°C/W when	ບ	ບ <b>ມ c)</b> 1	35°C/W w	hen		

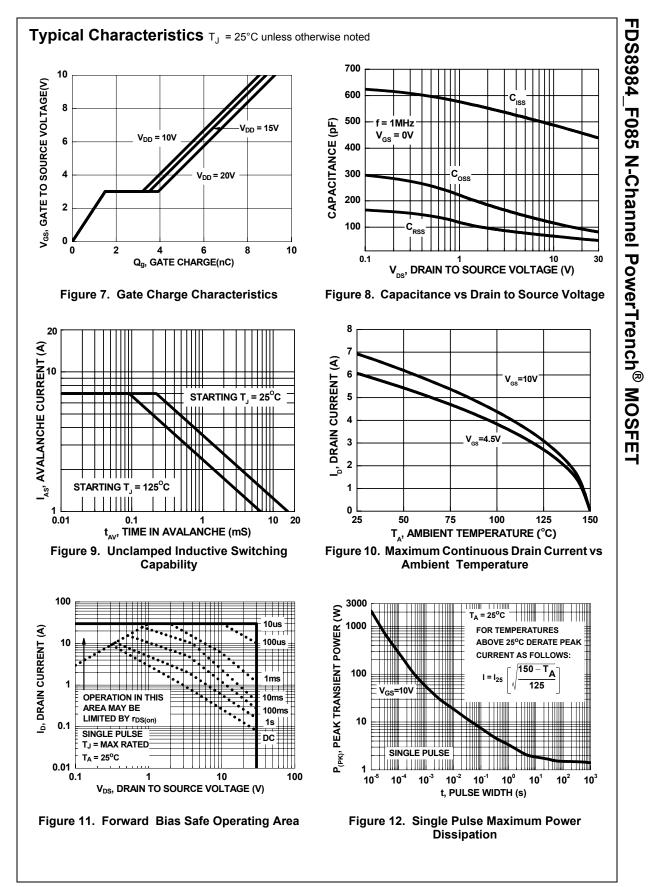
8690

Scale 1 : 1 on letter size paper

2: Starting  $T_J$  = 25°C, L = 1mH,  $I_{AS}$  = 8A,  $V_{DD}$  = 27V,  $V_{GS}$  = 10V. 3: Pulse Test:Pulse Width <300 $\mu$ S, Duty Cycle <2%.

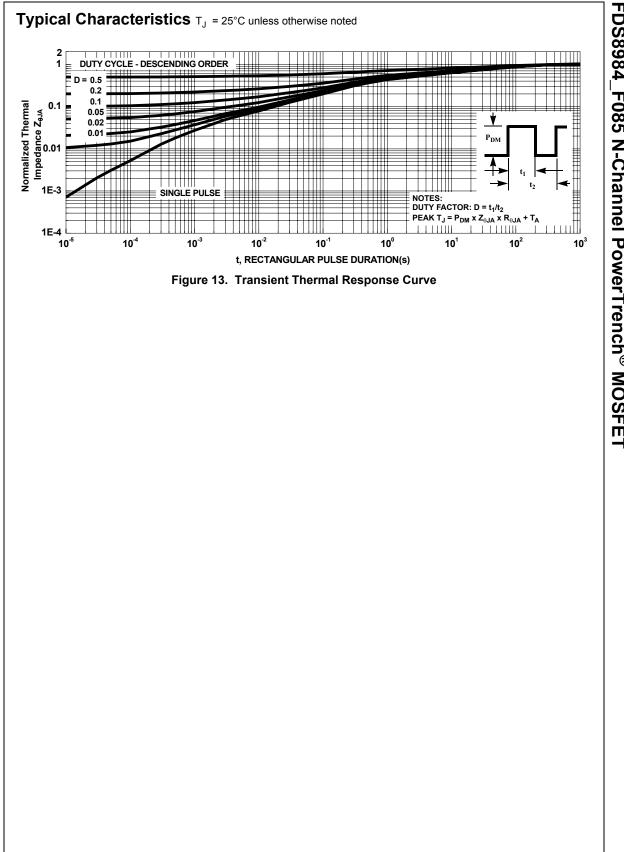


FDS8984\_F085 N-Channel PowerTrench<sup>®</sup> MOSFET



FDS8984\_F085 Rev. A

www.fairchildsemi.com





SEMICONDUCTOR

## TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not on exhaustive list of all such tradem

AccuPower™	FRFET <sup>®</sup>	PowerTrench <sup>®</sup>	The Power Franchise
Auto-SPM™	Global Power Resource <sup>SM</sup>	PowerXS™	the
Build it Now™	Green FPS™	Programmable Active Droop™	power
CorePLUS™	Green FPS™ e-Series™	QFET®	franchise TinyBoost™
CorePOWER™	G <i>max</i> ™	QS™	TinyBuck™
CROSSVOLT™	GTO™	Quiet Series <sup>™</sup>	TinyCalc™
CTL™	IntelliMAX™	RapidConfigure™	TinyLogic®
Current Transfer Logic™	ISOPLANAR™		TINYOPTO™
	MegaBuck™		TinyPower™
Dual Cool™_	MICROCOUPLER™	Saving our world, 1mW/W/kW at a time™	TinyPWM™
EcoSPARK <sup>®</sup>	MicroFET™	SignalWise™	TinyWire™
EfficentMax™	MicroPak™	SmartMax™	TriFault Detect™
R	MicroPak2™	SMART START™	TRUECURRENT™*
T	MillerDrive™	SPM®	μSerDes™
Fairchild <sup>®</sup>	MotionMax™	STEALTH™	μθειbes
Fairchild Semiconductor <sup>®</sup>	Motion-SPM <sup>™</sup>	SuperFET™	M
FACT Quiet Series™	OptiHiT™	SuperSOT™-3	UHC <sup>®</sup>
FACT <sup>®</sup>	OPTOLOGIC®	SuperSOT™-6	
FAST <sup>®</sup>	OPTOPLANAR®	SuperSOT™-8	Ultra FRFET™
FastvCore™	®	SupreMOS™	UniFET™ VCX™
FETBench™	U.	SyncFET™	
FlashWriter <sup>®</sup> *	PDP SPM™	Sync-Lock™	VisualMax™ XS™
FPS™	Power-SPM™	SYSTEM <sup>®*</sup>	V9
F-PFS™		GENERAL	

#### DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness

### ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

#### PRODUCT STATUS DEFINITIONS Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete Not In Production		Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. 147

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Fairchild Semiconductor: <u>FDS8984\_F085</u>